



**THE DATASHEET OF  
DF153-1250-15\_26MM**





**TET ESTEL AS**  
ESTONIA

**September**  
**2015**

**Series**  
**DF153-1250**

**Fast Recovery Press-Pack**  
**Diode**  
**Type DF153-1250**

For use as high-power inverters,  
fly-wheel diodes in DC choppers,  
power supplies as high frequency rectifier

Maximum mean forward current						$I_{FAV}$	<b>1250 A</b>		
Maximum repetitive peak reverse voltage						$U_{RRM}$	<b>800 ÷ 1500 V</b>		
Reverse recovery time						<b>trr</b>	<b>3,2; 4,0; 5,0 <math>\mu</math>s</b>		
$U_{RRM}$ , V	800	900	1000	1100	1200	1300	1400	1500	
Voltage code	8	9	10	11	12	13	14	15	
$T_{vj}$ , °C	- 60 ÷ 125								

**MAXIMUM ALLOWABLE RATINGS**

Symbols and parameters		Units	DF153-1250	Conditions
$I_{FAV}$	Mean forward current	A	1250 2105	$T_c=90^\circ\text{C}$ , $T_c=55^\circ\text{C}$ , 180° half-sine wave, 50 Hz
$I_{FRMS}$	RMS forward current	A	1960	$T_c=90^\circ\text{C}$
$I_{FSM}$	Surge forward current	kA	27 30	$T_{vj}=125^\circ\text{C}$ $T_{vj}=25^\circ\text{C}$ tp=10 ms
$I^2t$	Limiting load integral	$\text{kA}^2\text{s}$	3645 4500	$T_{vj}=125^\circ\text{C}$ $T_{vj}=25^\circ\text{C}$ UR=0
$U_{RRM}$	Repetitive peak reverse voltage	V	800÷1500	$T_j \text{ min} \leq T_{vj} \leq T_{jM}$ 180° half-sine wave, 50 Hz
$U_{RSM}$	Non-repetitive peak reverse voltage	V	880÷1600	$T_j \text{ min} \leq T_{vj} \leq T_{jM}$ 180° half-sine wave tp=10 ms, Single pulse
$T_{stg}$	Storage temperature	°C	-60÷80	
$T_{vj}$	Junction temperature	°C	-60÷125	

**CHARACTERISTICS**

$U_{FM}$	Peak forward voltage	V	1,6	$T_{vj}=25^\circ\text{C}$ , $I_{FM}=3,14 I_{FAV}$
$U_{F(TO)}$	Threshold voltage	V	1,1	$T_{vj}=125^\circ\text{C}$ $1,57 I_{FAV} < I_F < 4,71 I_{FAV}$
$R_T$	Forward slope resistance	$\text{m}\Omega$	0,11	
$I_{RRM}$	Repetitive peak reverse current	mA	75	$T_{vj}=125^\circ\text{C}$ , $U_R = U_{RRM}$

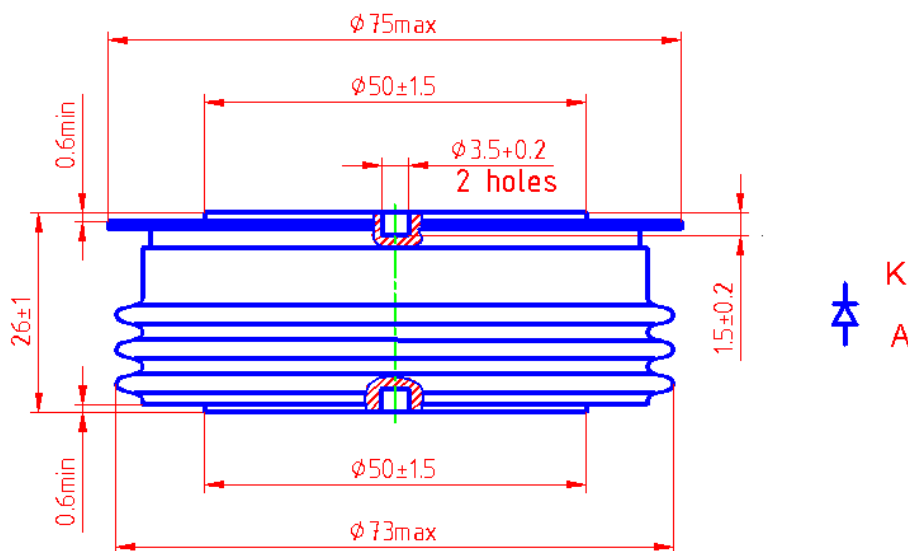
### CHARACTERISTICS

Symbols and parameters		Units	DF153-1250	Conditions
trr	Reverse recovery time	$\mu\text{s}$	3,2÷5,0 2,5÷4,0 2,0÷3,2	$T_{vj}=125^{\circ}\text{C}$ , $I_F=1250\text{A}$ , $U_R=100\text{V}$ $di_R / dt = 50\text{A}/\mu\text{s}$ $di_R / dt = 100\text{A}/\mu\text{s}$ $di_R / dt = 200\text{A}/\mu\text{s}$
Qrr	Recovered charge	$\mu\text{C}$	140÷240 220÷340 300÷480	$T_{vj}=125^{\circ}\text{C}$ , $I_F=1250\text{A}$ , $U_R=100\text{V}$ $di_R / dt = 50\text{A}/\mu\text{s}$ $di_R / dt = 100\text{A}/\mu\text{s}$ $di_R / dt = 200\text{A}/\mu\text{s}$
Rthjc	Thermal resistance junction to case	$^{\circ}\text{C}/\text{W}$	0,02	Direct current, double side cooled

### ORDERING

	DF	153	1250	12	3	
	1	2	3	4	5	



1. Fast recovery diode.
2. Design version.
3. Mean forward current, A.
4. Voltage code (12 = 1200 V).
5. Group of reverse recovery time ( $1 \leq 5 \mu\text{s}$ ;  $2 \leq 4 \mu\text{s}$ ;  $3 \leq 3,2 \mu\text{s}$ ).



Mounting force : 19 ÷ 28 kN  
Weight : 580 grams

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